

JS07B1GS10-2

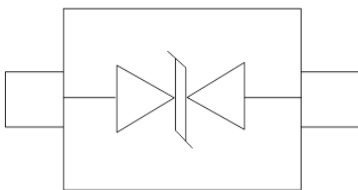
1-Line Bi-directional High Power TVS Diode



Description

The JS07B1GS10-2 is an bi-directional TVS diode, utilizing leading monolithic silicon technology to provide fast response time and low ESD clamping voltage, making this device an ideal solution for protecting voltage sensitive data and power lines. The JS07B1GS10-2 complies with the IEC 61000-4-2 (ESD) standard with $\pm 30\text{kV}$ air and $\pm 30\text{kV}$ contact discharge. It is assembled into a SOD-123FL lead-free package. The small size and high ESD/surge protection make JS07B1GS10-2 an ideal choice to protect cell phone, digital cameras, audio players and many other portable applications.

Circuit Diagram



Circuit and Pin Schematic

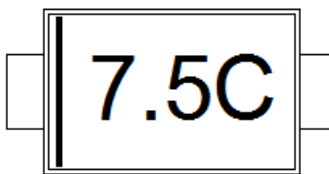
Features

- * 4500W peak pulse power (8/20 μs)
- * Low leakage
- * Operating voltage: 7V
- * Ultra low clamping voltage
- * One power line protects
- * Complies with following standards:
 - IEC 61000-4-2 (ESD) immunity test
 - Air discharge: $\pm 30\text{kV}$
 - Contact discharge: $\pm 30\text{kV}$
 - IEC61000-4-5 (Lightning) 200A (8/20 μs)
- * RoHS Compliant
- * Package: SOD-123FL

Applications

Fast-charge battery chargers
Power management system
Cellular Handsets and Accessories
Personal Digital Assistants
Notebooks and Handhelds
Portable Instrumentation
Digital Cameras

Marking Diagram



Transparent top view

7.5C:Device Marking Code

Ordering Information

Part Number	Packaging	Reel Size
JS07B1GS10-2	3000/Tape & Reel	7 inch

Absolute Maximum Ratings ($T_A=25^\circ\text{C}$ unless otherwise specified)

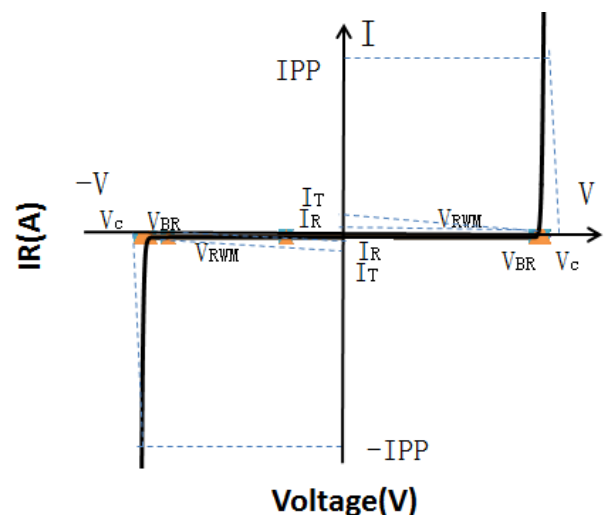
Parameter	Symbol	Value	Unit
Peak Pulse Power (8/20 μs)	Ppk	4500	W
Peak Pulse Current (8/20 μs)	IPP	200	A
ESD per IEC 61000-4-2 (Air)	VESD	± 30	kV
ESD per IEC 61000-4-2 (Contact)		± 30	
Operating Temperature Range	TJ	-55 to +125	$^\circ\text{C}$
Storage Temperature Range	Tstg	-55 to +150	$^\circ\text{C}$

Electrical Characteristics ($T_A=25^\circ\text{C}$ unless otherwise specified)

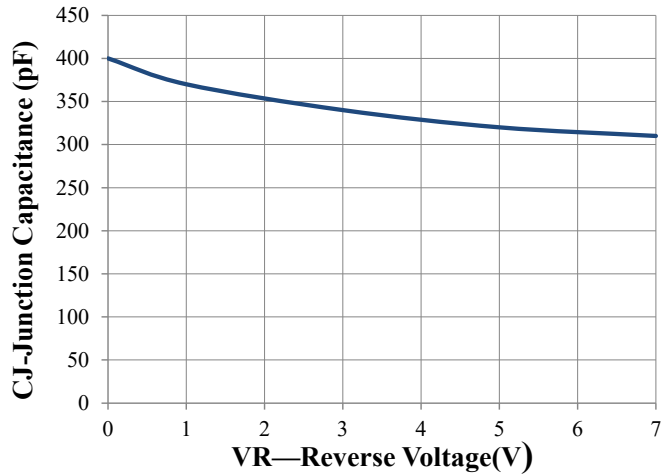
Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Reverse Working Voltage	V_{RWM}				7	V
Breakdown Voltage	V_{BR}	$I_{\text{T}} = 1\text{mA}$	7.5			V
Reverse Leakage Current	I_{R}	$V_{\text{RWM}} = 7\text{V}$			5.0	μA
Clamping Voltage	V_{C}	$I_{\text{PP}} = 150\text{A}$ (8 x 20 μs pulse)		19.0		V
Clamping Voltage	V_{C}	$I_{\text{PP}} = 200\text{A}$ (8 x 20 μs pulse)		23.0		V
Junction Capacitance	C_{J}	$V_{\text{R}} = 0\text{V}$, $f = 1\text{MHz}$		400	500	pF

Portion Electronics Parameter

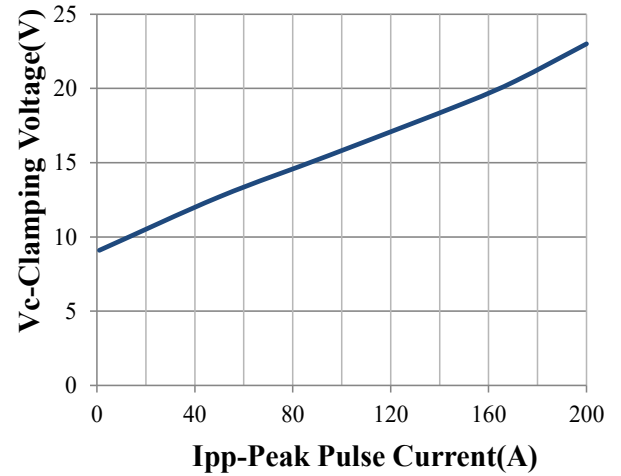
Symbol	Parameter
I_{T}	Test Current
I_{PP}	Maximum Reverse Peak Pulse Current
V_{C}	Clamping Voltage @ I_{C}



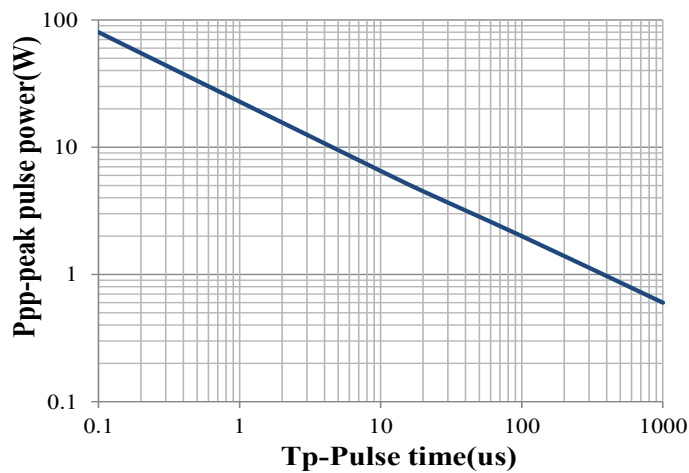
Typical Performance Characteristics ($T_A=25^\circ\text{C}$ unless otherwise Specified)



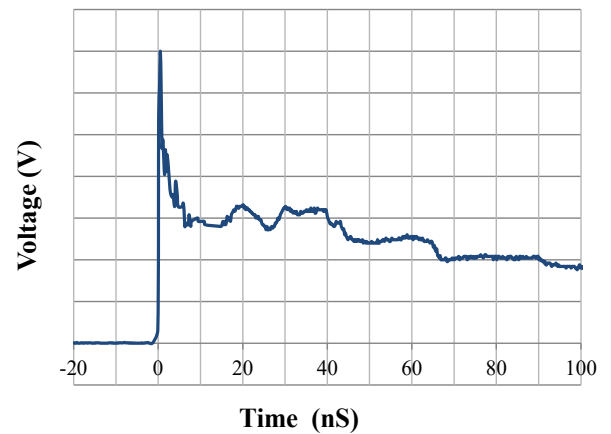
Junction Capacitance vs. Reverse Voltage



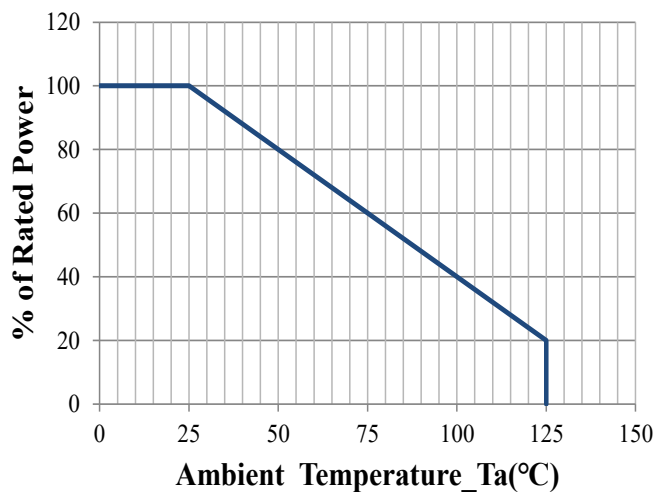
Clamping Voltage vs. Peak Pulse Current



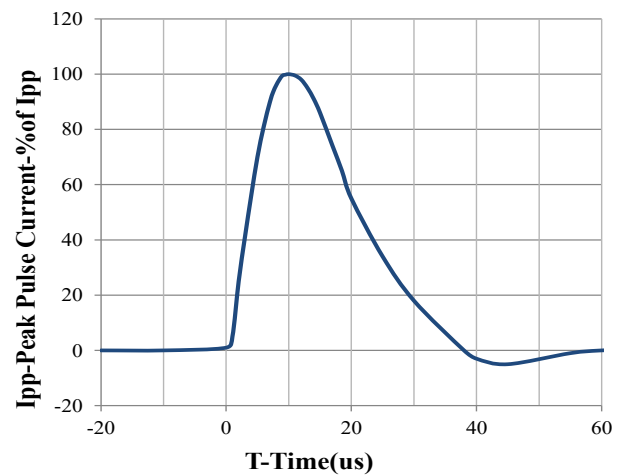
Peak Pulse Power vs. Pulse Time



IEC61000-4-2 Pulse Waveform

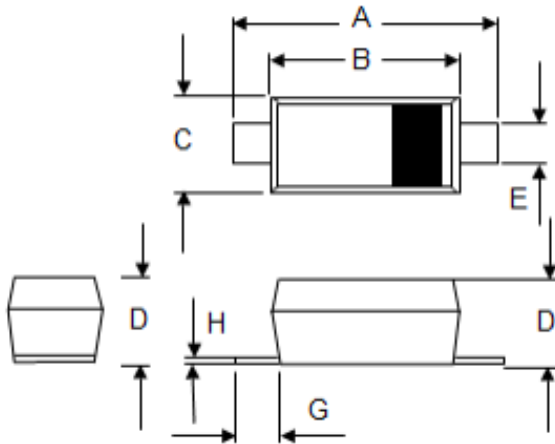


Power Derating Curve



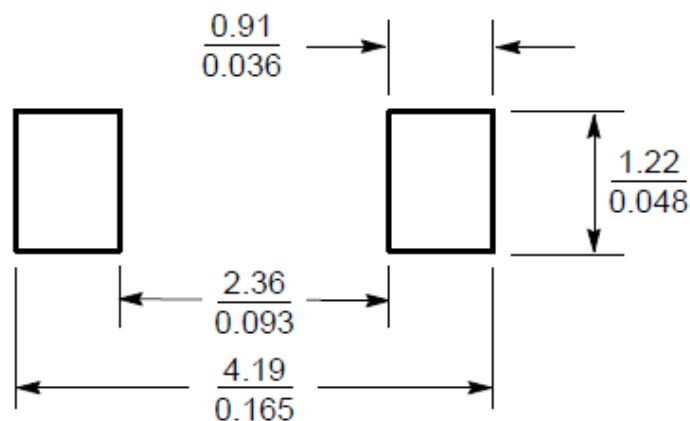
8 X 20us Pulse Waveform

SOD-123FL Package Outline Drawing (Dimensions in millimeters)



SYM	DIMENSIONS					
	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	3.4	3.7	3.95	0.142	0.148	0.155
B	2.5	2.7	2.90	0.098	0.106	0.114
C	1.4	1.70	1.95	0.055	0.066	0.077
D	1.10	1.15	1.20	0.044	0.046	0.048
E	0.5	0.80	1.10	0.020	0.031	0.043
G	0.25	—	—	0.010	—	—
H	—	—	0.20	—	—	0.008

Suggested Land Pattern



SCALE 10:1 $\left(\frac{\text{mm}}{\text{inches}} \right)$

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